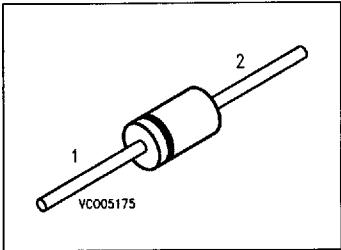


Silicon Variable Capacitance Diodes

BB 505 B
BB 505 G

- For UHF and VHF tuners
- Not for new design



Type	Marking	Ordering Code	Pin Configuration	Package ¹⁾
BB 505 B	orange	Q62702-B37		DO-35 DHD
BB 505 G		Q62702-B270		

Maximum Ratings

Parameter	Symbol	Values	Unit
Reverse voltage	V_R	28	V
Peak reverse voltage	V_{RM}	30	
Forward current, $T_A \leq 60\text{ }^\circ\text{C}$	I_F	20	mA
Operating temperature range	T_{op}	- 55 ... + 100	$^\circ\text{C}$
Storage temperature range	T_{stg}	- 55 ... + 150	

1) For detailed information see chapter Package Outlines.

Electrical Characteristics

 at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Reverse current $V_R = 28\text{ V}$ $V_R = 28\text{ V}, T_A = 60\text{ }^{\circ}\text{C}$	I_R	— —	— —	20 0.5	nA μA
Diode capacitance, $f = 1\text{ MHz}$ BB 505 B: $V_R = 1\text{ V}$ $V_R = 28\text{ V}$ BB 505 G: $V_R = 1\text{ V}$ $V_R = 28\text{ V}$	C_T	— 1.85 — 1.8	17.5 — 17.5 —	— 2.25 — 2.4	pF
Capacitance ratio, $V_R = 1\text{ V}, 28\text{ V}; f = 1\text{ MHz}$ BB 505 B BB 505 G	$\frac{C_{T1}}{C_{T28}}$	7.7 7.5	— —	9.4 9.5	—
Capacitance matching $V_R = 0.5\text{ V} \dots 28\text{ V}$	$\frac{\Delta C_T}{C_T}$	—	—	3	%
Series resistance, $C_T = 9\text{ pF}, f = 470\text{ MHz}$ BB 505 B BB 505 G	r_s	— —	— —	0.7 1	Ω
Series inductance	L_s	—	3	—	nH
Temperature coefficient of diode capacitance $V_R = 1\text{ V}, f = 1\text{ MHz}$	TC_C	—	480	—	ppm/K

Diode capacitance $C_T = f(V_R)$

$f = 1 \text{ MHz}$

